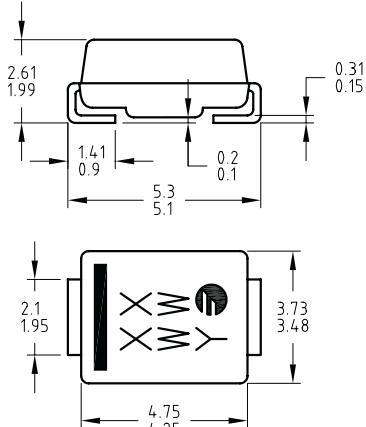


## 1 Amp. Surface Mount Schottky Barrier Rectifiers

 <b>RoHS</b> COMPLIANCE <b>CASE:</b> <b>SMB/DO-214AA</b>  XX = Marking code WW = Week code Y = Year code <b>Dimensions in mm.</b>	<b>Voltage</b> <b>20 V to 150 V</b> <b>Current</b> <b>1.0 A</b> <ul style="list-style-type: none"> <li>• For surface mounted application</li> <li>• Easy pick and place</li> <li>• Metal to silicon rectifier, majority carrier conduction</li> <li>• Low power loss, high efficiency</li> <li>• High current capability, low VF</li> <li>• High surge current capability</li> <li>• Plastic material used carriers Underwriters Laboratory Classification 94V-0</li> <li>• Epitaxial construction</li> <li>• High temperature soldering: 260 °C / 10 seconds at terminals</li> </ul> <b>MECHANICAL DATA</b> Case: Molded plastic Terminals: Pure tin plated, lead free Polarity: Indicated by cathode band Packaging: 16 mm tape EIA-STD RS-481. Weight: 0.093 g.
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### Maximum Ratings and Electrical Characteristics at 25 °C

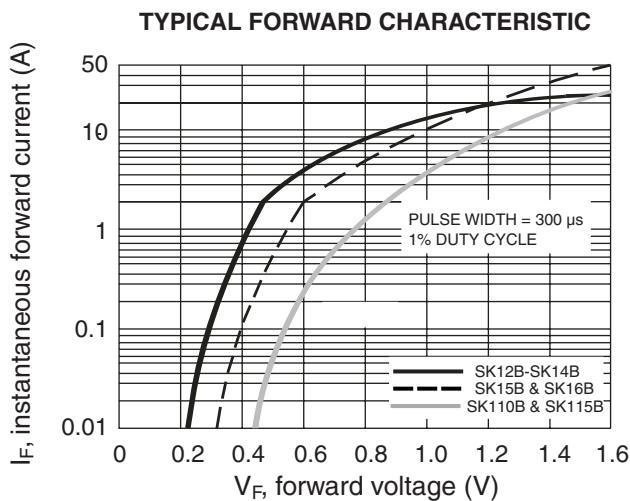
		SK 12B	SK 13B	SK 14B	SK 15B	SK 16B	SK 19B	SK 110B	SK 115B
	Marking code	I1	I2	I3	I4	I5	I6	I7	I8
$V_{RRM}$	Maximum Recurrent Peak Reverse Voltage (V)	20	30	40	50	60	90	100	150
$V_{RMS}$	Maximum RMS Voltage (V)	14	21	28	35	42	63	70	105
$V_{DC}$	Maximum DC Blocking Voltage (V)	20	30	40	50	60	90	100	150
$I_{F(AV)}$	Maximum Average Forward Rectified Current at $T_L$ (See graphic)	1.0 A							
$I_{FSM}$	8.3 ms.Pk Forward Surge Current (Jedec Method)	30 A							
$T_j$	Operating Temperature Range	-55°C to +125°C		-55°C to +150°C					
$T_{stg}$	Storage Temperature Range	-55°C to +150°C							

### Electrical Characteristics at Tamb = 25 °C

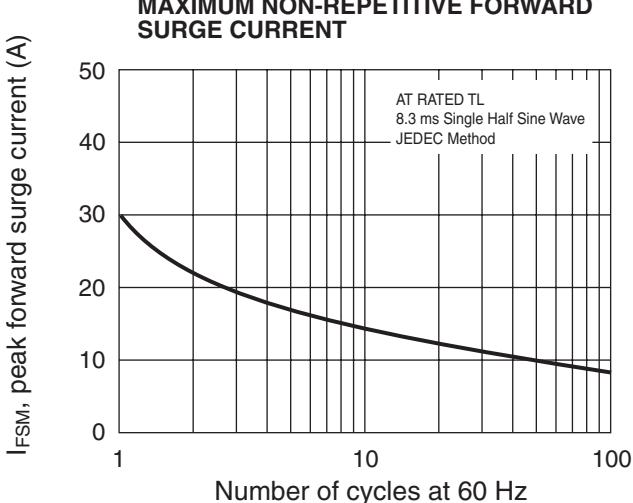
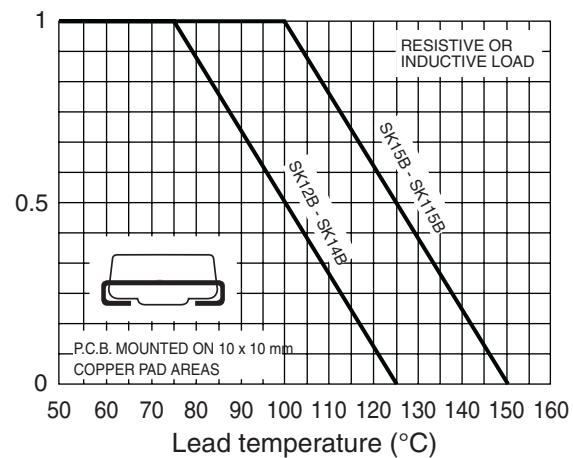
$V_F$	Maximum Instantaneous Forward Voltage @ 1.0 A	0.5 V	0.75 V	0.85 V	0.95 V		
$I_R$	Maximum DC Reverse Current (Note 1) $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_A = 100^\circ\text{C}$ $T_A = 125^\circ\text{C}$	0.5 mA		0.1 mA			
		10 mA	5.0 mA	--			
		--		2.0 mA			
$C_j$	Typical Junction Capacitance (Note 2)	110 pF					
$R_{thj-I}$	Typical Thermal Resistance (Note 3)	25 °C/W					

- NOTES:
1. Pulse Test With PW = 300 μsec, 1% Duty Cycle
  2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
  3. Measured on P.C. Board with 10mm x10mm Copper Pad Areas

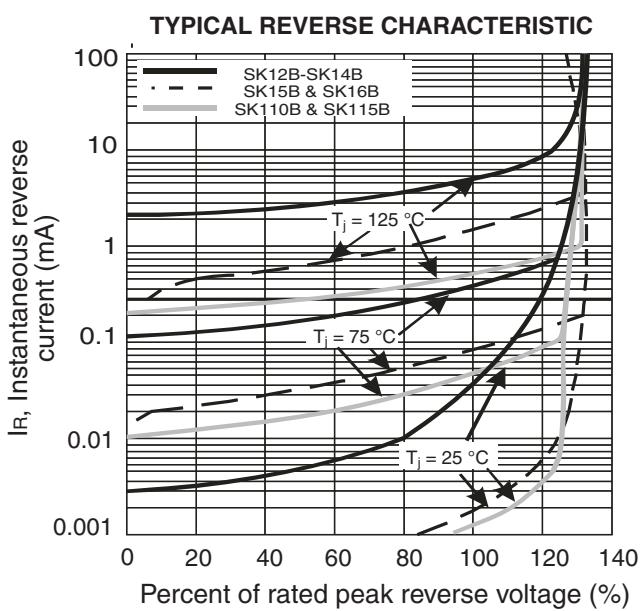
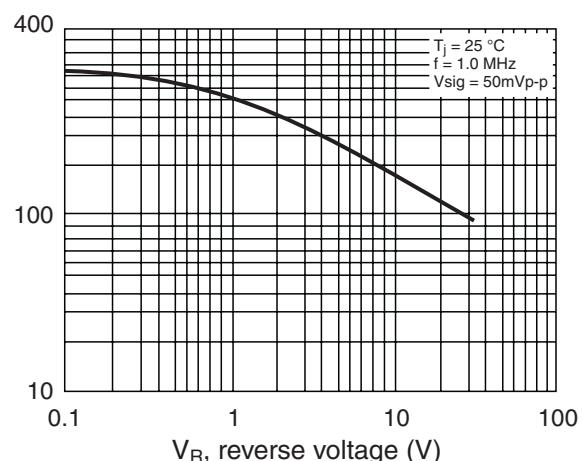
## Rating And Characteristic Curves



### MAXIMUM FORWARD CURRENT DERATING CURVE



### TYPICAL JUNCTION CAPACITANCE



### TYPICAL TRANSIENT THERMAL CHARACTERISTIC

